

# Superlattice phonons of graphene on hexagonal boron nitride

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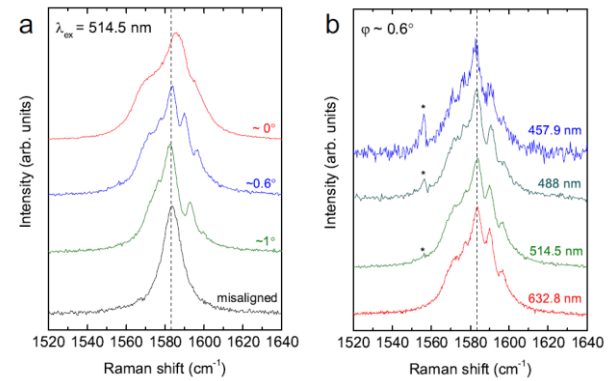
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Heterostructures based on vertical stacks of layered materials, such as graphene, hexagonal boron nitride (hBN) and transition metal dichalcogenides, constitute a new family of materials with physical properties that can be tuned to enable emerging electrical and optical devices [1]. The graphene/hBN stack can show a Moiré pattern due to a lattice mismatch,  $a_{\text{hBN}}/a_{\text{G}} - 1 \approx 1.8\%$  between the lattice constants of hBN ( $a_{\text{hBN}}$ ) and graphene ( $a_{\text{G}}$ ) [2-6]. The periodic potential perturbation on graphene results in a superlattice that generates a zone-folded phonon structure which strongly depends on the stacking angle  $\varphi$ , the relative rotation angle of graphene lattice with respect to hBN lattice. Raman spectroscopy on single layer graphene (SLG) on hBN with small stacking angles ( $< 1^\circ$ ) can probe the superlattice phonons of SLG/hBN heterostructure which correspond to the zone-folded phonons of the longitudinal optical (LO) and transverse optical (TO) branches. The zone-folded phonons give rise to multiple Raman peaks close to the G peak, whereby their peak positions strongly depend on the stacking angle as shown in Fig.1. We map the distinctive phonon dispersion of graphene near the  $\Gamma$  point of Brillouin zone (BZ), which is characterised by a kink of the LO phonon branch at the  $\Gamma$  point of BZ due to the Kohn anomaly. We estimated the electron-phonon interaction of LO phonon at  $\Gamma$  point which is a key role for various physical properties of graphene.

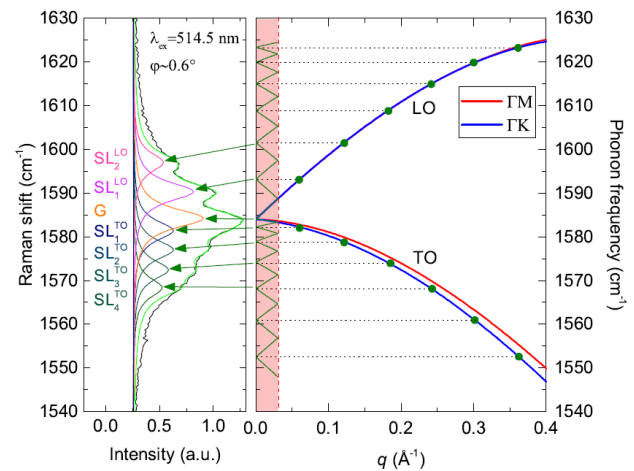
## References

- [1] F. Bonaccorso et al., *Materials Today* 12, 564 (2012).
- [2] J. Xue et al., *Nat. Mater.* 10 (2011) 282.
- [3] M. Yankowitz et al., *Nat. Phys.* 8 (2012) 382.
- [4] S. Tang et al., *Scientific Rep.* 3 (2013) 2666.
- [5] C. R. Wood. et al., *Nat. Phys.* 10 (2014) 451.
- [6] M. Yankowitz et al., *Nat. Comm.* 7, (2016) 13168.

## Figures



**Figure 1:** Raman spectra of the G peak (a) on different stacking angles with a 514.5 nm laser excitation and (b) on 0.6° stacking angle with different laser excitations.



**Figure 2:** Zone-folding of superlattice phonons near the  $\Gamma$  point of Brillouin zone (BZ) for 0.6° stacking angle